FAIRCHILD SEMICONDUCTOR™

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# CD4503BC
# Hex Non-Inverting 3-STATE Buffer

## General Description

The CD4503BC is a hex non-inverting 3-STATE buffer with high output current sink and source capability. 3-STATE outputs make it useful in bus-oriented applications. Two separate disable inputs are provided. Buffers 1 through 4 are controlled by the disable 4 input. Buffers 5 and 6 are controlled by the disable 2 input. A high level on either disable input will cause those gates on its control line to go into a high impedance state.

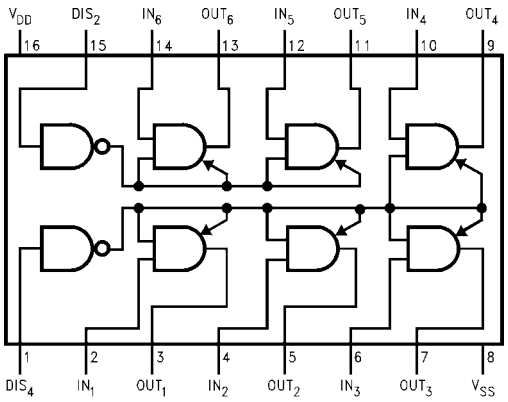
## Features

- Wide supply voltage range: 3.0 $V_{DC}$ to 18 $V_{DC}$
- 3-STATE outputs
- Symmetrical turn on/turn off delays
- Symmetrical output rise and fall times
- Pin-for-pin replacement for MM80C97 and MC14503

## Ordering Code:

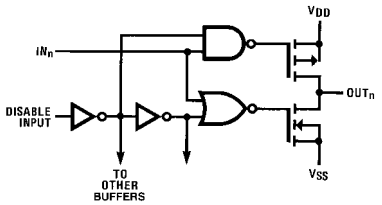
| Order Number | Package Number | Package Description |
|---|---|---|
| CD4503BCM | M16A | 16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow |
| CD4503BCN | N16E | 16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide |

## Connection Diagram




**Top View**

## Schematic Diagram




## Truth Table

| In | Disable Input | Out |
|---|---|---|
| 0 | 0 | 0 |
| 1 | 0 | 1 |
| X | 1 | 3-STATE |

X = Don't Care

## Absolute Maximum Ratings (Note 1)

(Note 2)

| | |
|---|---|
| Supply Voltage ($V_{DD}$) | −0.5V to +18V |
| Input Voltage ($V_{IN}$) | −0.5V to +0.5V |
| Storage Temperature Range ($T_S$) | −65°C to +150°C |
| Power Dissipation ($P_D$) | |
| Dual-In-Line | 700 mW |
| Small Outline | 500 mW |
| Lead Temperature ($T_L$) | |
| (Soldering, 10 seconds) | 260°C |

## Recommended Operating Conditions (Note 2)

| | |
|---|---|
| Supply Voltage ($V_{DD}$) | +3V to +15V |
| Operating Temperature Range ($T_A$) | −55°C to +125°C |

**Note 1:** "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.

**Note 2:** $V_{SS}$ = 0V unless otherwise specified.

## DC Electrical Characteristics (Note 2)

| Symbol | Parameter | Conditions | −55°C | | +25°C | | | +125°C | | Units |
|---|---|---|---|---|---|---|---|---|---|---|
| | | | Min | Max | Min | Typ | Max | Min | Max | |
| $I_{DD}$ | Quiescent Device Current | $V_{DD}$ = 5V, $V_{IN}$ = $V_{DD}$ or $V_{SS}$ | | 1 | | | 1 | | 30 | µA |
| | | $V_{DD}$ = 10V, $V_{IN}$ = $V_{DD}$ or $V_{SS}$ | | 2 | | | 2 | | 60 | |
| | | $V_{DD}$ = 15V, $V_{IN}$ = $V_{DD}$ or $V_{SS}$ | | 4 | | | 4 | | 120 | |
| $V_{OL}$ | LOW Level Output Voltage | $V_{IN}$ = $V_{DD}$ or 0 | | | | | | | | V |
| | | $V_{DD}$ = 5V | | 0.05 | | 0 | 0.05 | | 0.05 | |
| | | $V_{DD}$ = 10V | | 0.05 | | 0 | 0.05 | | 0.05 | |
| | | $V_{DD}$ = 15V | | 0.05 | | 0 | 0.05 | | 0.05 | |
| $V_{OH}$ | HIGH Level Output Voltage | $V_{IN}$ = $V_{DD}$ or 0 | | | | | | | | V |
| | | $V_{DD}$ = 5V | 4.95 | | 4.95 | 5 | | 4.95 | | |
| | | $V_{DD}$ = 10V | 9.95 | | 9.95 | 10 | | 9.95 | | |
| | | $V_{DD}$ = 15V | 14.95 | | 14.95 | 15 | | 14.95 | | |
| $V_{IL}$ | LOW Level Input Voltage | $V_{DD}$ = 5V, $V_O$ = 4.5V or 0.5V | | 1.5 | | 2.25 | 1.5 | | 1.5 | V |
| | | $V_{DD}$ = 10V, $V_O$ = 9.0V or 1.0V | | 3.0 | | 4.50 | 3.0 | | 3.0 | |
| | | $V_{DD}$ = 15V, $V_O$ = 13.5V or 1.5V | | 4.0 | | 6.75 | 4.0 | | 4.0 | |
| $V_{IH}$ | HIGH Level Input Voltage | $V_{DD}$ = 5V, $V_O$ = 0.5V or 4.5V | 3.5 | | 3.5 | 2.75 | | 3.5 | | V |
| | | $V_{DD}$ = 10V, $V_O$ = 1.0V or 9.0V | 7.0 | | 7.0 | 5.5 | | 7.0 | | |
| | | $V_{DD}$ = 15V, $V_O$ = 1.5V or 13.5V | 11.0 | | 11.0 | 8.25 | | 11.0 | | |
| $I_{OL}$ | LOW Level Output Current | $V_{DD}$ = 4.5V, $V_{OL}$ = 0.4V | 2.8 | | 2.3 | 2.55 | | 1.60 | | mA |
| | | $V_{DD}$ = 5.0V, $V_{OL}$ = 0.4V | 3.0 | | 2.4 | 2.75 | | 1.75 | | |
| | | $V_{DD}$ = 10V, $V_{OL}$ = 0.5V | 7.85 | | 6.35 | 7.00 | | 4.45 | | |
| | | $V_{DD}$ = 15V, $V_{OL}$ = 1.5V | 19.95 | | 16.10 | 25.00 | | 11.30 | | |
| $I_{OH}$ | HIGH Level Output Current | $V_{DD}$ = 5V, $V_{OH}$ = 4.6V | −1.28 | | −1.02 | −1.76 | | −0.7 | | mA |
| | | $V_{DD}$ = 10V, $V_{OH}$ = 9.5V | −3.20 | | −2.60 | −4.5 | | −1.8 | | |
| | | $V_{DD}$ = 15V, $V_{OH}$ = 13.5V | −8.20 | | −6.80 | −17.6 | | −4.8 | | |
| $I_{OZ}$ | 3-STATE Leakage Current | $V_{DD}$ = 15V | | ±0.1 | | $\pm 10^{-4}$ | ±0.1 | | ±1.0 | µA |
| $I_{IN}$ | Input Current | $V_{DD}$ = 15V | | ±0.1 | | $\pm 10^{-4}$ | ±0.1 | | ±1.0 | µA |

**Note 3:** $I_{OH}$ and $I_{OL}$ are tested one output at a time.

## AC Electrical Characteristics (Note 4)

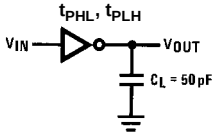
$T_A = 25°C$, $C_L = 50$ pF, $R_L = 200$ kΩ, Input $t_r = t_f = 20$ ns, unless otherwise specified

| Symbol | Parameter | Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| $t_{PHL}$, $t_{PLH}$ | Propagation Delay Time | $V_{DD} = 5V$ | | 75 | 100 | |
| | | $V_{DD} = 10V$ | | 35 | 40 | ns |
| | | $V_{DD} = 15V$ | | 25 | 30 | |
| $t_{PLZ}$, $t_{PHZ}$ | Propagation Delay Time, | $V_{DD} = 5V$ | | 80 | 125 | |
| | Logical Level to HIGH | $V_{DD} = 10V$ | | 40 | 90 | ns |
| | Impedance State | $V_{DD} = 15V$ | | 35 | 70 | |
| $t_{PZL}$, $t_{PZH}$ | Propagation Delay Time, | $V_{DD} = 5V$ | | 95 | 175 | |
| | High Impedance State to | $V_{DD} = 10V$ | | 40 | 80 | ns |
| | Logical Level | $V_{DD} = 15V$ | | 35 | 70 | |
| $t_{TLH}$ | Output Rise Time | $V_{DD} = 5V$ | | 45 | 80 | |
| | | $V_{DD} = 10V$ | | 23 | 40 | ns |
| | | $V_{DD} = 15V$ | | 18 | 35 | |
| $t_{THL}$ | Output Fall Time | $V_{DD} = 5V$ | | 45 | 80 | |
| | | $V_{DD} = 10V$ | | 23 | 40 | ns |
| | | $V_{DD} = 15V$ | | 18 | 35 | |

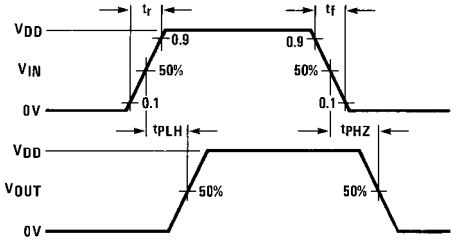
**Note 4:** AC Parameters are guaranteed by DC correlated testing.

## AC Test Circuits and Switching Time Waveforms

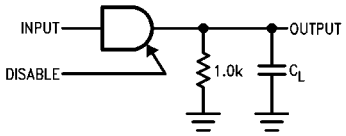
$t_{PHL}$, $t_{PLH}$



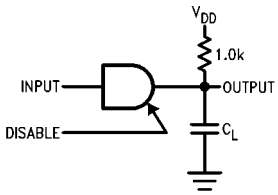

CMOS to CMOS



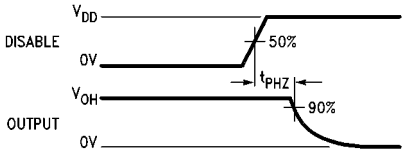

$t_{PHZ}$ and $t_{PZH}$



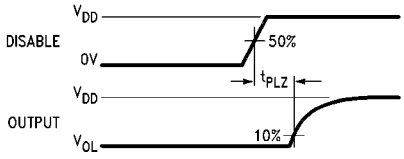

$t_{PLZ}$ and $t_{PZL}$



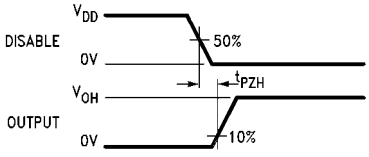

$t_{PHZ}$



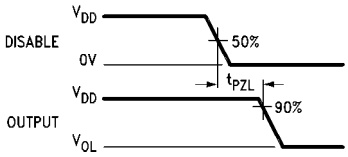

$t_{PLZ}$




$t_{PZH}$

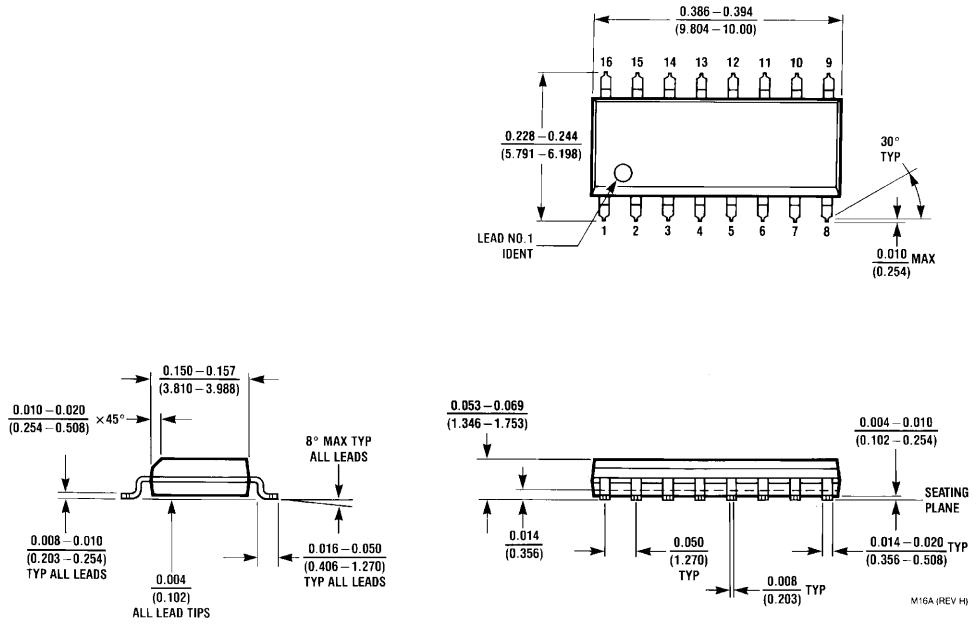



$t_{PZL}$



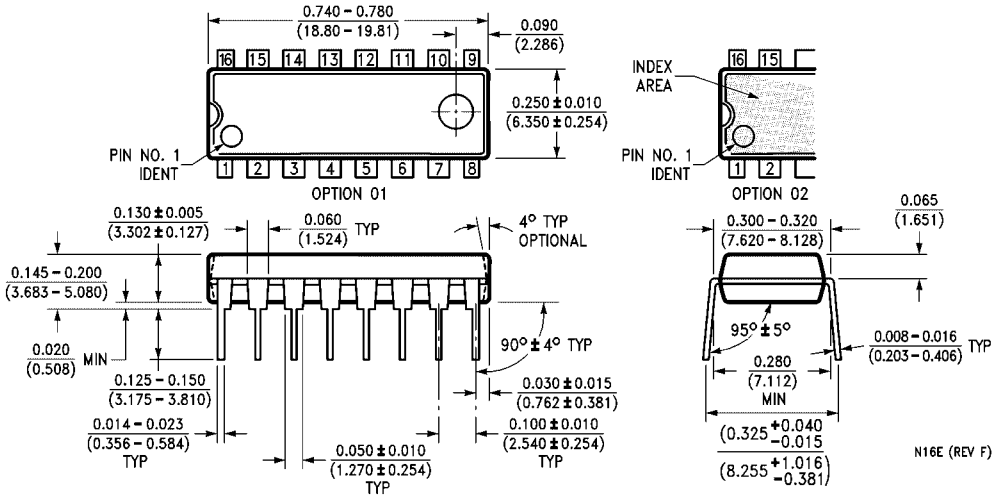

**Note:** Delays measured with input $t_r$, $t_f \leq 20$ ns.

## Physical Dimensions inches (millimeters) unless otherwise noted




**16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow**
**Package Number M16A**

## Physical Dimensions inches (millimeters) unless otherwise noted (Continued)




**16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide**
**Package Number N16E**